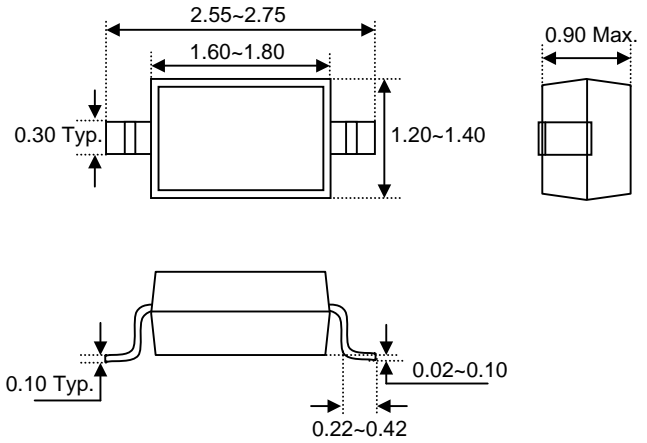


## IV. Zener Diode

### SMD Zener Diode (200mW) BZT52C2V0S~BZT52C75S

(Package: SOD-323)

<p><b>FEATURES</b></p> <ul style="list-style-type: none"> <li>• Planar die construction.</li> <li>• 200mW power dissipation.</li> <li>• General purpose, medium current.</li> <li>• Ideally suited for automated assembly processes.</li> </ul> <p><b>MECHANICAL DATA</b></p> <ul style="list-style-type: none"> <li>• Case : Molded plastic, SOD-323.</li> <li>• Mounting position : Any</li> <li>• Polarity : Color band denotes cathode</li> </ul> <p><b>DEVICE MARKING CODE</b></p> <ul style="list-style-type: none"> <li>• See Table on next page.</li> </ul>	 <p>Case: SOD-323 Dimensions in millimeters</p>
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## Ratings & Electrical Characteristics

Ratings at 25 unless otherwise specified.			
Characteristic	Symbol	Value	Unit
Forward voltage @ $I_F=10\text{mA}$	$V_F$	0.9	Volts
Power dissipation	$P_D$	200	mW
Thermal resistance, junction to ambient air	$R_{th-JA}$	625	/W
Junction temperature	$T_j$	+150	
Storage temperature range	$T_{stg}$	-65 to +150	

Notes:

1. Valid provided that device terminals are kept at ambient temperature.
2. Short duration test pulse used in minimize self-heating effect.
3.  $f = 1\text{KHz}$

**IV. Zener Diode**

**SMD Zener Diode (200mW)**

**BZT52C2V0S~BZT52C75S**

**(Package: SOD-323)**

Type Number	Marking Code	Zener Voltage Range				Maximum Zener Impedance			Maximum Reverse Current		Typical Temperature Coefficient @I <sub>ZTC</sub> mV/	
		V <sub>Z</sub> @I <sub>ZT</sub>			I <sub>ZT</sub>	Z <sub>ZT</sub> @I <sub>ZT</sub>	Z <sub>ZK</sub> @I <sub>ZK</sub>	I <sub>ZK</sub>	I <sub>R</sub>	@V <sub>R</sub>	Min	Max
		Nom(V)	Min(V)	Max(V)	mA			mA	µA	V		
BZT52C2V0S	WY	2.00	1.91	2.09	5	100	600	1.0	150	1.0	-3.5	0
BZT52C2V4S	WX	2.4	2.2	2.6	5	100	600	1.0	50	1.0	-3.5	0
BZT52C2V7S	W1	2.7	2.5	2.9	5	100	600	1.0	20	1.0	-3.5	0
BZT52C3V0S	W2	3.0	2.8	3.2	5	95	600	1.0	10	1.0	-3.5	0
BZT52C3V3S	W3	3.3	3.1	3.5	5	95	600	1.0	5.0	1.0	-3.5	0
BZT52C3V6S	W4	3.6	3.4	3.8	5	90	600	1.0	5.0	1.0	-3.5	0
BZT52C3V9S	W5	3.9	3.7	4.1	5	90	600	1.0	3.0	1.0	-3.5	0
BZT52C4V3S	W6	4.3	4.0	4.6	5	90	600	1.0	3.0	1.0	-3.5	0
BZT52C4V7S	W7	4.7	4.4	5.0	5	80	500	1.0	3.0	2.0	-3.5	0.2
BZT52C5V1S	W8	5.1	4.8	5.4	5	60	480	1.0	2.0	2.0	-2.7	1.2
BZT52C5V6S	W9	5.6	5.2	6.0	5	40	400	1.0	1.0	2.0	-2.0	2.5
BZT52C6V2S	WA	6.2	5.8	6.6	5	10	150	1.0	3.0	4.0	0.4	3.7
BZT52C6V8S	WB	6.8	6.4	7.2	5	15	80	1.0	2.0	4.0	1.2	4.5
BZT52C7V5S	WC	7.5	7.0	7.9	5	15	80	1.0	1.0	5.0	2.5	5.3
BZT52C8V2S	WD	8.2	7.7	8.7	5	15	80	1.0	0.7	5.0	3.2	6.2
BZT52C9V1S	WE	9.1	8.5	9.6	5	15	100	1.0	0.5	6.0	3.8	7.0
BZT52C10S	WF	10	9.4	10.6	5	20	150	1.0	0.2	7.0	4.5	8.0
BZT52C11S	WG	11	10.4	11.6	5	20	150	1.0	0.1	8.0	5.4	9.0
BZT52C12S	WH	12	11.4	12.7	5	25	150	1.0	0.1	8.0	6.0	10.0
BZT52C13S	WI	13	12.4	14.1	5	30	170	1.0	0.1	8.0	7.0	11.0
BZT52C15S	WJ	15	13.8	15.6	5	30	200	1.0	0.1	10.5	9.2	13.0
BZT52C16S	WK	16	15.3	17.1	5	40	200	1.0	0.1	11.2	10.4	14.0
BZT52C18S	WL	18	16.8	19.1	5	45	225	1.0	0.1	12.6	12.4	16.0
BZT52C20S	WM	20	18.8	21.2	5	55	225	1.0	0.1	14.0	14.4	18.0
BZT52C22S	WN	22	20.8	23.3	5	55	250	1.0	0.1	15.4	16.4	20.0
BZT52C24S	WO	24	22.8	25.6	5	70	250	1.0	0.1	16.8	18.4	22.0
BZT52C27S	WP	27	25.1	28.9	2	80	300	0.5	0.1	18.9	21.4	25.3
BZT52C30S	WQ	30	28.0	32.0	2	80	300	0.5	0.1	21.0	24.4	29.4
BZT52C33S	WR	33	31.0	35.0	2	80	325	0.5	0.1	23.1	27.4	33.4
BZT52C36S	WS	36	34.0	38.0	2	90	350	0.5	0.1	25.2	30.4	37.4
BZT52C39S	WT	39	37.0	41.0	2	130	350	0.5	0.1	27.3	33.4	41.2
BZT52C43S	WU	43	40.0	46.0	5	100	700	1.0	0.1	32.0	10.0	12.0
BZT52C47S	WV	47	44.0	50.0	5	100	750	1.0	0.1	35.0	10.0	12.0
BZT52C51S	WW	51	48.0	54.0	5	100	750	1.0	0.1	38.0	10.0	12.0
BZT52C56S	WX	56	53.2	58.8	2	200	400	0.5	0.045	39.2	10.0	12.0
BZT52C62S	WY	62	58.9	65.1	2	215	423	0.5	0.045	43.4	10.0	12.0
BZT52C68S	WZ	68	64.6	71.4	2	240	447	0.5	0.045	47.6	10.0	12.0
BZT52C75S	6H	75	71.25	78.75	2	255	470	0.5	0.045	52.5	10.0	12.0

Notes :

1. Valid provided that device terminals are kept at ambient temperature.
2. Tested with pulses, period = 5ms, pulse width = 300µs.
3. f = 1KHz

**Ratings and Characteristic Curves of BZT52C2V0S~BZT52C75S**

